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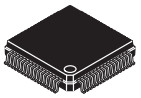
MC9S08GW64 Series

Covers: MC9S08GW64 and MC9S08GW32



80-LQFP
Case 917A
14 × 14

64-LQFP
Case 840F
10 × 10

8-Bit HCS08 Central Processor Unit (CPU)

- New version of S08 core with same performace as traditional S08 and lower power
- Up to 20 MHz CPU at 3.6 V to 2.15 V and up to 10 MHz CPU at 3.6 V to 1.8 V, across temperature range of –40 °C to 85 °C
- HC08 instruction set with added BGND instruction
- Support for up to 48 interrupt/reset sources

On-Chip Memory

- Flash read/program/erase over full operating voltage and temperature
- Random-access memory (RAM)
- Security circuitry to prevent unauthorized access to RAM and flash contents

Power-Saving Modes

- Two low power stop modes and reduced power wait mode
- Low power run and wait modes allow peripherals to run while voltage regulator is in standby
- Peripheral clock gating register can disable clocks to unused modules, thereby reducing currents
- Very low power external oscillator that can be used in stop2 or stop3 modes to provide accurate clock source to real time counter
- 6 µs typical wakeup time from stop3 mode

Clock Source Options

- Oscillator (XOSC1) — Loop-control Pierce oscillator; Crystal or ceramic resonator of 32.768 kHz; Clock source for iRTC or ICS
- Oscillator (XOSC2) — Loop-control Pierce oscillator; Crystal or ceramic resonator range of 31.25 kHz to 38.4 kHz or 1 MHz to 16 MHz; optional clock source for ICS
- Internal Clock Source (ICS) — Internal clock source module containing a frequency-locked-loop (FLL) controlled by internal or external reference (XOSC1, XOSC2); precision trimming of internal reference allows 0.2% resolution and 2% deviation over temperature and voltage; supporting CPU/bus frequencies from 1 MHz to 20 MHz

System Protection

- Watchdog computer operating properly (COP) reset with option to run from dedicated 1 kHz internal clock source or bus clock
- Low-voltage warning with interrupt
- Low-voltage detection with reset or interrupt
- Illegal opcode and illegal address detection with reset
- Flash block protection

Development Support

- Single-wire background debug interface
- Breakpoint capability to allow single breakpoint setting during in-circuit debugging (plus 3 more breakpoints in breakpoint unit)
- Breakpoint (BKPT) debug module containing three comparators (A, B, and C) with ability to match addresses in 64 KB space. Each comparator can be used as hardware breakpoint. Full mode, Comparator A compares address and Comparator B compares data. Supports both tag and force breakpoints

Peripherals

- **LCD** — up to 4×40 or 8×36 LCD driver with internal charge pump and option to provide an internally regulated LCD reference that can be trimmed for contrast control
- **ADC16** — two analog-to-digital converters; 16-bit resolution; one dedicated differential per ADC; up to 16-ch; up to 2.5 µs conversion time for 12-bit mode; automatic compare function; hardware averaging; calibration registers; temperature sensor; internal bandgap reference channel; operation in stop3; fully functional from 3.6 V to 1.8 V
- **PRACMP** —three rail to rail programmable reference analog comparator; up to 8 inputs; on-chip programmable reference generator output; selectable interrupt on rising, falling, or either edge of comparator output; operation in stop3
- **SCI** — four full duplex non-return to zero (NRZ); LIN master extended break generation; LIN slave extended break detection; wakeup on active edge; SCI0 designed for AMR operation; TxD of SCI1 and SCI2 can be modulated with timers and RxD can recieved through PRACMP;
- **SPI**— three full-duplex or single-wire bidirectional; double-buffered transmit and receive; master or slave mode; MSB-first or LSB-first shifting; SPI0 designed for AMR opeartion
- **IIC** — up to 100 kbps with maximum bus loading; multi-master operation; programmable slave address; interrupt driven byte-by-byte data transfer; supporting broadcast mode and 10-bit addressing; supporting SM BUS functionality; can wake from stop3
- **FTM** — 2-channel flextimer module; selectable input capture, output compare, or buffered edge- or center-aligned PWM on each channel
- **IRTC** — independent real-time clock, independent power domain, 32 bytes RAM, 32.768 kHz input clock optional output to ICS, hardware calendar, hardware compensation due to crystal or temperature characteristics, tamper detection and indicator
- **PCRC** — 16/32 bit programmable cyclic redundancy check for high-speed CRC calculation
- **MTIM** — two 8-bit and one 16-bit timers; configurable clock inputs and interrupt generation on overflow
- **PDB** — programmable delay block; optimized for scheduling ADC conversions
- **PCNT** — position counter; working in stop3 mode without waking CPU; can be used to generate waveforms like timer

Input/Output

- 57 GPIOs including one output-only pin
- Eight KBI interrupts with selectable polarity
- Hysteresis and configurable pullup device on all input pins; configurable slew rate and drive strength on all output pins.

Package Options

- 80-pin LQFP, 64-pin LQFP

This document contains information on a product under development. Freescale reserves the right to change or discontinue this product without notice.

Table of Contents

Revision History

To provide the most up-to-date information, the revision of our documents on the World Wide Web will be the most current. Your printed copy may be an earlier revision. To verify you have the latest information available, refer to:

http://freescale.com/

The following revision history table summarizes changes contained in this document.

Rev	Date	Description of Changes
1	5/26/2010	Initial public release
2	10/29/2010	Completed all the TBDs. Updated the voltage output data in the Table 20. Changed the classification marking of $\|I_{InT}\|$ to C in the Table 8.
3	1/28/2011	Updated Table 7.

Related Documentation

Find the most current versions of all documents at: http://www.freescale.com

Reference Manual (MC9S08GW64RM)

Contains extensive product information including modes of operation, memory, resets and interrupts, register definition, port pins, CPU, and all module information.

1 Devices in the MC9S08GW64 Series

Table 1 summarizes the feature set available in the MC9S08GW64 series of MCUs.

Table 1. MC9S08GW64 Series Features by MCU and Package

Feature	MC9S08GW64		MC9S08GW32	
Package	**80-pin LQFP**	**64-pin LQFP**	**80-pin LQFP**	**64-pin LQFP**
FLASH	65,536 Bytes		32,768 Bytes	
RAM	4,032 Bytes		2,048 Bytes	
ADC0[1] Single-ended Channels	7-ch	7-ch	7-ch	7-ch
ADC0 Differential Channels[2]	1	0	1	0
ADC1 Single-ended Channels	7-ch	7-ch	7-ch	7-ch
ADC1 Differential Channels	1	1	1	1
BKPT	yes		yes	
ICS	yes		yes	
IIC	yes		yes	
IRQ	yes		yes	
IRTC	yes		yes	
KBI	8-ch		8-ch	
MTIM8	2		2	
MTIM16	yes		yes	
PCNT	yes		yes	
PCRC	yes		yes	
PDB	yes		yes	
PRACMP	3		3	
SCI	4		4	
SPI	3		3	
FTM	2-ch		2-ch	
LCD	8×36 4×40	8×24 4×28	8×36 4×40	8×24 4×28
VREFO	yes	yes	yes	yes
XOSC	2		2	
I/O pins[3]	57	45	57	45

1 There are two 16-bit ADC modules, so two parallel conversions at two channels can be made simultaneously.
2 Each differential channel consists of two pins (DADPx and DADMx).
3 The I/O pins include one output-only pin.

The block diagram in Figure 1 shows the structure of the MC9S08GW64 series MCUs.

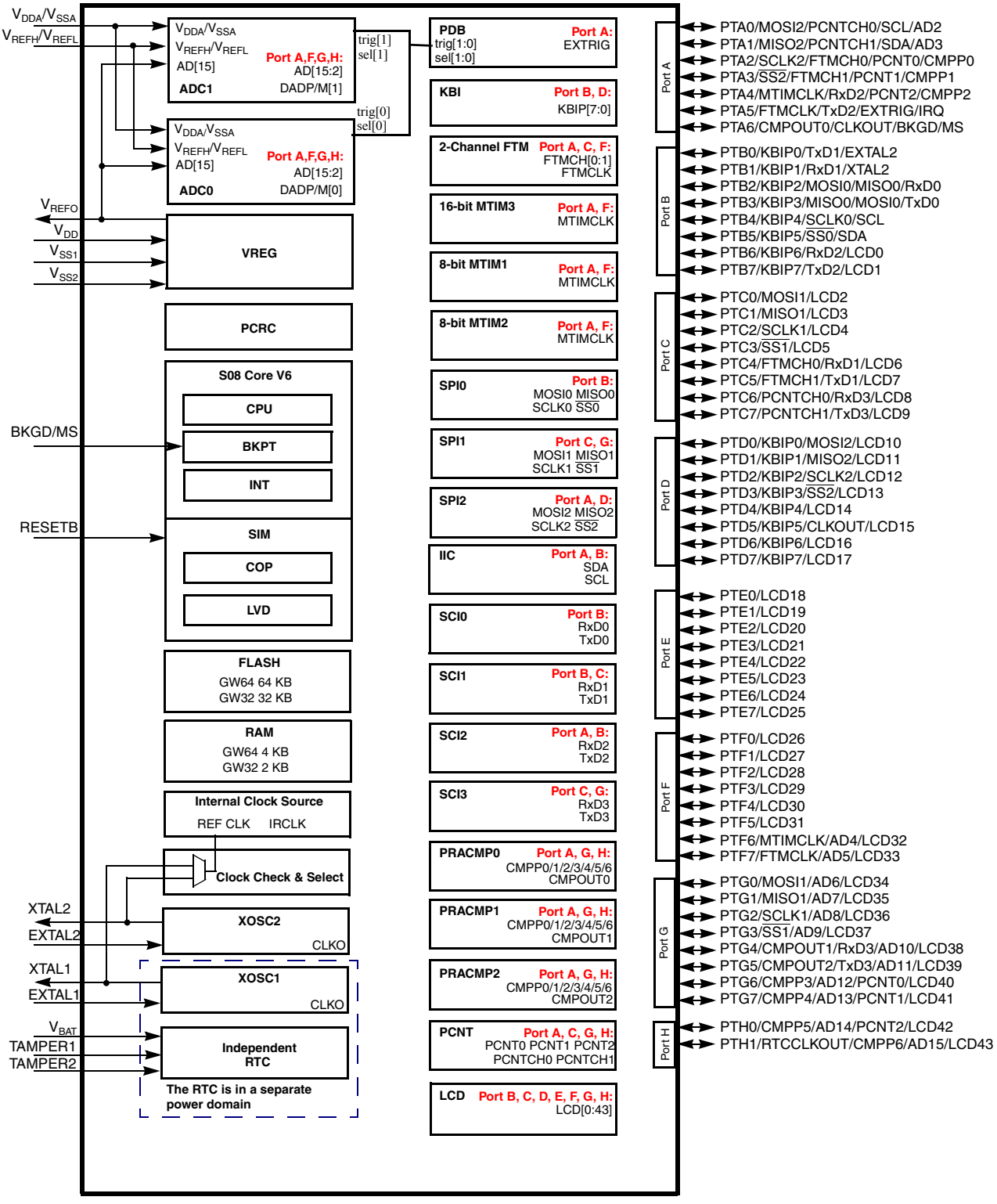


Figure 1. MC9S08GW64 Series Block Diagram

2 Pin Assignments

This section shows the pin assignments for the MC9S08GW64 series devices.

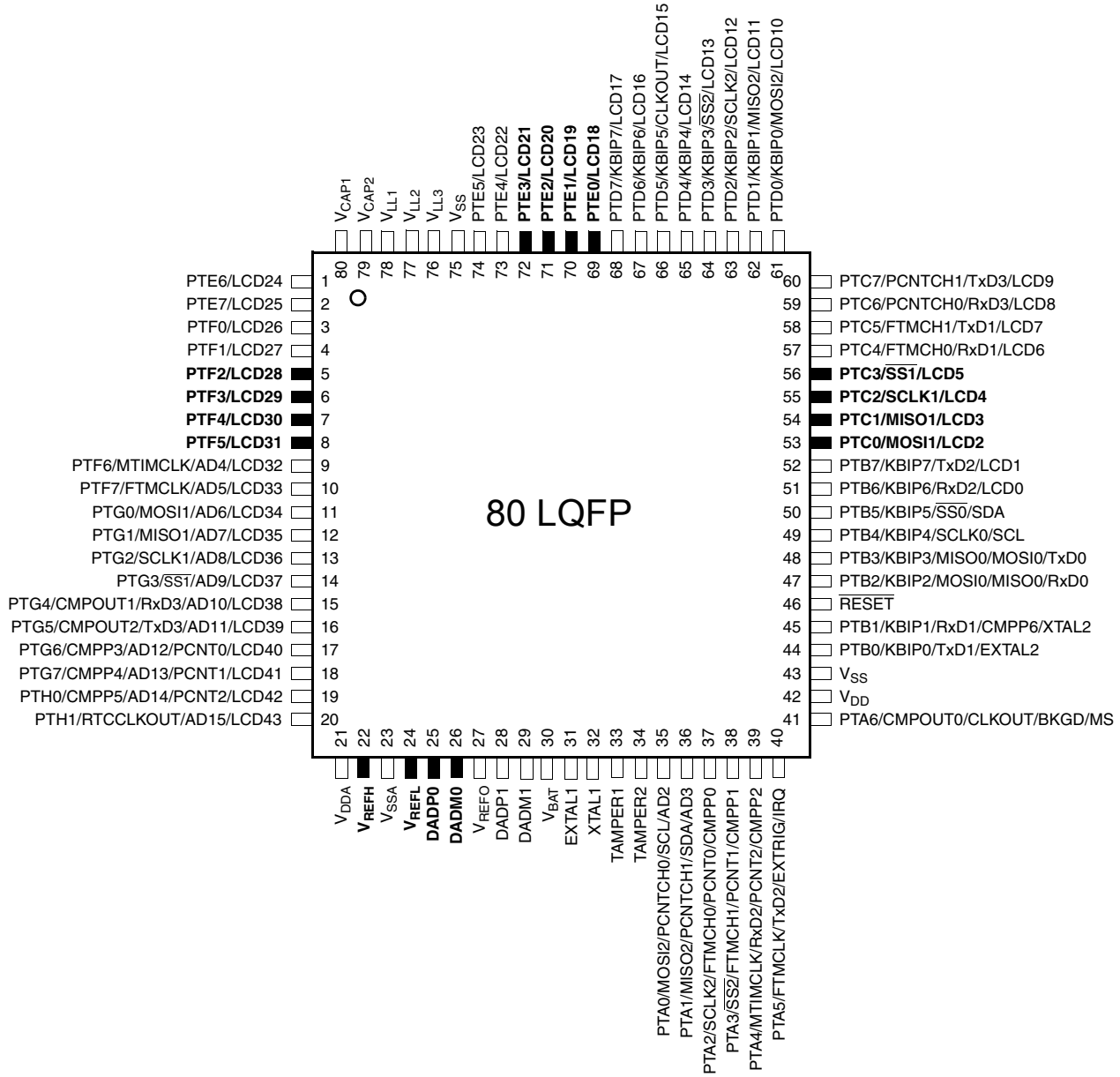


Figure 2. MC9S08GW64 Series in 80-Pin LQFP Package

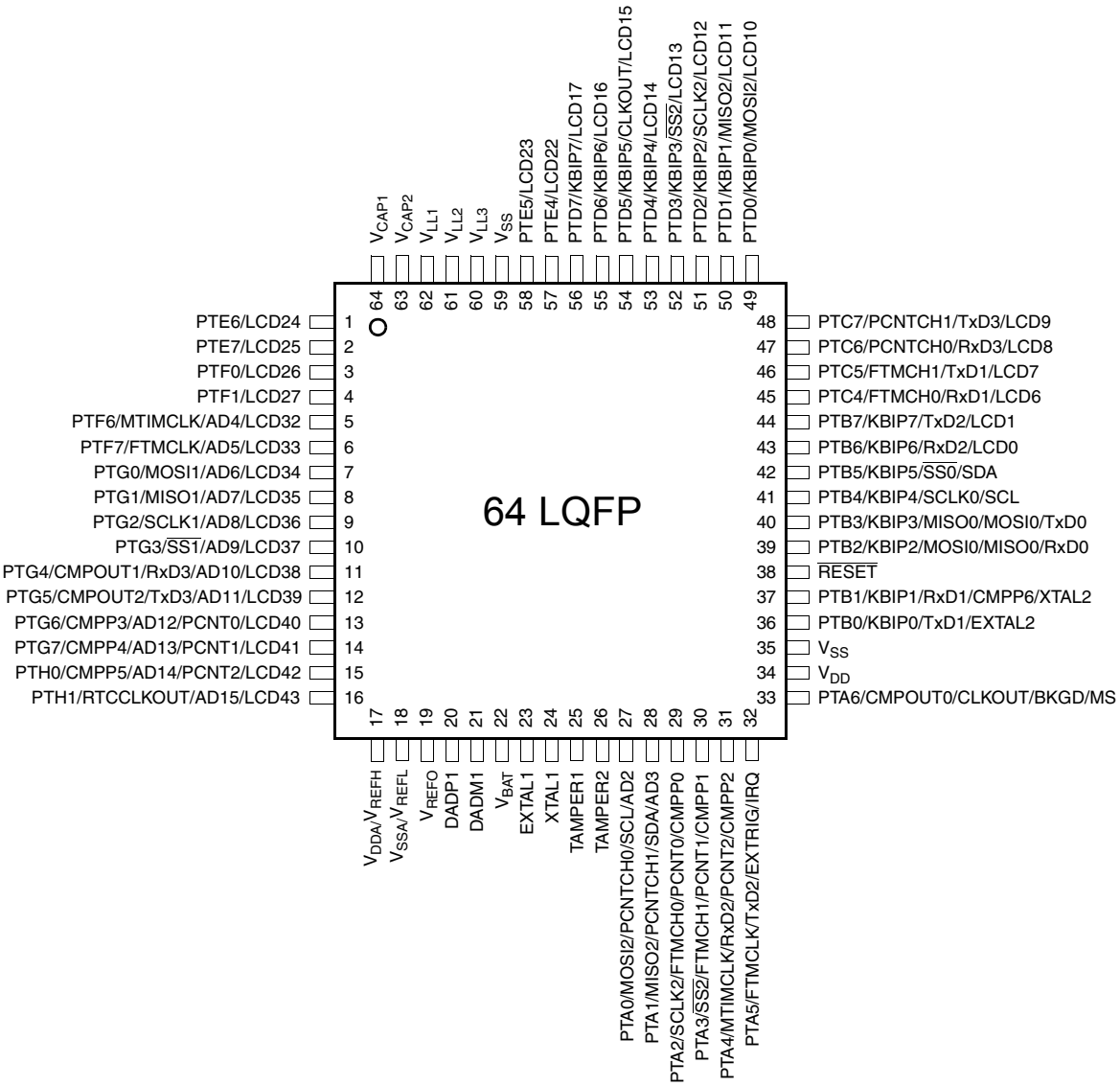


Figure 3. MC9S08GW64 Series in 64-Pin LQFP Package

Table 2. Pin Availability by Package Pin-Count

80	64	Port Pin	Default func	Alt 1	Alt 2	Alt3	Alt4
1	1	PTE6	PTE6		LCD24		
2	2	PTE7	PTE7		LCD25		
3	3	PTF0	PTF0	LCD26			
4	4	PTF1	PTF1	LCD27			
5		PTF2	PTF2	LCD28			
6		PTF3	PTF3	LCD29			

Table 2. Pin Availability by Package Pin-Count (continued)

80	64	Port Pin	Default func	Alt 1	Alt 2	Alt3	Alt4
7		PTF4	PTF4	LCD30			
8		PTF5	PTF5	LCD31			
9	5	PTF6	PTF6	MTIMCLK	AD4	LCD32	
10	6	PTF7	PTF7	FTMCLK	AD5	LCD33	
11	7	PTG0	PTG0	MOSI1	AD6	LCD34	
12	8	PTG1	PTG1	MISO1	AD7	LCD35	
13	9	PTG2	PTG2	SCLK1	AD8	LCD36	
14	10	PTG3	PTG3	$\overline{SS1}$	AD9	LCD37	
15	11	PTG4	PTG4	CMPOUT1	RxD3	AD10	LCD38
16	12	PTG5	PTG5	CMPOUT2	TxD3	AD11	LCD39
17	13	PTG6	PTG6	CMPP3	AD12	PCNT0	LCD40
18	14	PTG7	PTG7	CMPP4	AD13	PCNT1	LCD41
19	15	PTH0	PTH0	CMPP5	AD14	PCNT2	LCD42
20	16	PTH1	PTH1	RTCCLKOUT	AD15	LCD43	
21	17	V_{DDA}	V_{DDA}				
22		V_{REFH}	V_{REFH}				
23	18	V_{SSA}	V_{SSA}				
24		V_{REFL}	V_{REFL}				
25		DADP0	DADP0				
26		DADM0	DADM0				
27	19	V_{REFO}	V_{REFO}				
28	20	DADP1	DADP1				
29	21	DADM1	DADM1				
30	22	V_{BAT}	V_{BAT}				
31	23	EXTAL1	EXTAL1				
32	24	XTAL1	XTAL1				
33	25	TAMPER1[1]	TAMPER1				
34	26	TAMPER2	TAMPER2				
35	27	PTA0	PTA0	MOSI2	PCNTCH0	SCL	AD2
36	28	PTA1	PTA1	MISO2	PCNTCH1	SDA	AD3
37	29	PTA2	PTA2	SCLK2	FTMCH0	PCNT0	CMPP0
38	30	PTA3	PTA3	$\overline{SS2}$	FTMCH1	PCNT1	CMPP1
39	31	PTA4	PTA4	MTIMCLK	RxD2	PCNT2	CMPP2
40	32	PTA5[2]	PTA5	FTMCLK	TxD2	EXTRIG	IRQ
41	33	PTA6[3]	BKGD/MS	CMPOUT0	CLKOUT	BKGD/MS	

Table 2. Pin Availability by Package Pin-Count (continued)

80	64	Port Pin	Default func	Alt 1	Alt 2	Alt3	Alt4
42	34	V_{DD}	V_{DD}				
43	35	V_{SS}	V_{SS}				
44	36	PTB0	PTB0	KBIP0	TxD1	EXTAL2	
45	37	PTB1[1]	PTB1	KBIP1	RxD1	CMPP6	XTAL2
46	38	$\overline{\text{RESET}}$	$\overline{\text{RESET}}$				
47	39	PTB2	PTB2	KBIP2	MOSI0	MISO0	RxD0
48	40	PTB3[4]	PTB3	KBIP3	MISO0	MOSI0	TxD0
49	41	PTB4[3]	PTB4	KBIP4	SCLK0	SCL	
50	42	PTB5[3]	PTB5	KBIP5	$\overline{\text{SS0}}$	SDA	
51	43	PTB6	PTB6	KBIP6	RxD2	LCD0	
52	44	PTB7	PTB7	KBIP7	TxD2	LCD1	
53		PTC0	PTC0	MOSI1	LCD2		
54		PTC1	PTC1	MISO1	LCD3		
55		PTC2	PTC2	SCLK1	LCD4		
56		PTC3	PTC3	$\overline{\text{SS1}}$	LCD5		
57	45	PTC4	PTC4	FTMCH0	RxD1	LCD6	
58	46	PTC5	PTC5	FTMCH1	TxD1	LCD7	
59	47	PTC6	PTC6	PCNTCH0	RxD3	LCD8	
60	48	PTC7	PTC7	PCNTCH1	TxD3	LCD9	
61	49	PTD0	PTD0	KBIP0	MOSI2	LCD10	
62	50	PTD1	PTD1	KBIP1	MISO2	LCD11	
63	51	PTD2	PTD2	KBIP2	SCLK2	LCD12	
64	52	PTD3	PTD3	KBIP3	$\overline{\text{SS2}}$	LCD13	
65	53	PTD4	PTD4	KBIP4	LCD14		
66	54	PTD5	PTD5	KBIP5	CLKOUT	LCD15	
67	55	PTD6	PTD6	KBIP6	LCD16		
68	56	PTD7	PTD7	KBIP7	LCD17		
69		PTE0	PTE0	LCD18			
70		PTE1	PTE1	LCD19			
71		PTE2	PTE2	LCD20			
72		PTE3	PTE3	LCD21			
73	57	PTE4	PTE4		LCD22		
74	58	PTE5	PTE5		LCD23		
75	59	V_{SS}	V_{SS}				
76	60	V_{LL3}	V_{LL3}				

Table 2. Pin Availability by Package Pin-Count (continued)

80	64	Port Pin	Default func	Alt 1	Alt 2	Alt3	Alt4
77	61	V_{LL2}	V_{LL2}				
78	62	V_{LL1}	V_{LL1}				
79	63	V_{CAP2}	V_{CAP2}				
80	64	V_{CAP1}	V_{CAP1}				

1 TAMPER0 pin is dedicatedly used for Battery Removal Tamper and not exposed on any SoC pins.

2 PTA5 is with double drive strength.

3 PTA6 is an output-only pin when it is configured as GPIO.

4 PTB2, PTB3 and PTB4 are compatible with 5 V devices with a pullup device.

3 Electrical Characteristics

3.1 Introduction

This section contains electrical and timing specifications for the MC9S08GW64 sries of microcontrollers available at the time of publication.

3.2 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

Table 3. Parameter Classifications

P	Those parameters are guaranteed during production testing on each individual device.
C	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
T	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

NOTE

The classification is shown in the column labeled “C” in the parameter tables where appropriate.

3.3 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in Table 4 may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this section.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this

high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either V_{SS} or V_{DD}) or the programmable pull-up resistor associated with the pin is enabled.

Table 4. Absolute Maximum Ratings

Rating	Symbol	Value	Unit
Supply voltage	V_{DD}	–0.3 to +3.8	V
Maximum current into V_{DD}	I_{DD}	120	mA
Digital input voltage	V_{In}	–0.3 to V_{DD} + 0.3	V
Instantaneous maximum current Single pin limit (applies to all port pins except PTA5 and PTB1)[1, 2, 3]	I_D	± 25	mA
Instantaneous maximum current Single pin limit (applies to PTA5 and PTB1)[1,2,3]	I_D	± 50	mA
Storage temperature range	T_{stg}	–55 to 150	°C

1 Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V_{DD}) and negative (V_{SS}) clamp voltages, then use the larger of the two resistance values.

2 All functional non-supply pins are internally clamped to V_{SS} and V_{DD}.

3 Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{In} > V_{DD}$) is greater than I_{DD}, the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure external V_{DD} load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if the clock rate is very low (which would reduce overall power consumption).

3.4 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} will be very small.

Table 5. Thermal Characteristics

Rating	Symbol	Value	Unit
Operating temperature range (packaged)	T_A	T_L to T_H –40 to 85	°C
Maximum junction temperature	T_J	95	°C
Thermal resistance Single-layer board			
80-pin LQFP	θ_{JA}	61	°C/W
64-pin LQFP		70	
Thermal resistance Four-layer board			
80-pin LQFP	θ_{JA}	48	°C/W
64-pin LQFP		52	

The average chip-junction temperature (T_J) in °C can be obtained from:

$$T_J = T_A + (P_D \times \theta_{JA}) \quad \textit{Eqn. 1}$$

where:

T_A = Ambient temperature, °C
θ_{JA} = Package thermal resistance, junction-to-ambient, °C/W
$P_D = P_{int} + P_{I/O}$
$P_{int} = I_{DD} \times V_{DD}$, Watts — chip internal power
$P_{I/O}$ = Power dissipation on input and output pins — user determined

For most applications, $P_{I/O} << P_{int}$ and can be neglected. An approximate relationship between P_D and T_J (if $P_{I/O}$ is neglected) is:

$$P_D = K \div (T_J + 273°C) \quad \textit{Eqn. 2}$$

Solving Equation 1 and Equation 2 for K gives:

$$K = P_D \times (T_A + 273°C) + \theta_{JA} \times (P_D)^2 \quad \textit{Eqn. 3}$$

where K is a constant pertaining to the particular part. K can be determined from equation 3 by measuring P_D (at equilibrium) for a known T_A. Using this value of K, the values of P_D and T_J can be obtained by solving Equation 1 and Equation 2 iteratively for any value of T_A.

3.5 ESD Protection and Latch-Up Immunity

Although damage from electrostatic discharge (ESD) is much less common on these devices than on early CMOS circuits, normal handling precautions should be taken to avoid exposure to static discharge. Qualification tests are performed to ensure that these devices can withstand exposure to reasonable levels of static without suffering any permanent damage.

All ESD testing is in conformity with AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits. During the device qualification, ESD stresses were performed for the human body model (HBM), the machine model (MM) and the charge device model (CDM).

A device is defined as a failure if after exposure to ESD pulses the device no longer meets the device specification. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless instructed otherwise in the device specification.

Table 6. ESD and Latch-up Test Conditions

Model	Description	Symbol	Value	Unit
Human Body Model	Series resistance	R1	1500	Ω
	Storage capacitance	C	100	pF
	Number of pulses per pin	—	3	
Charge Device Model	Series resistance	R1	0	Ω
	Storage capacitance	C	200	pF
	Number of pulses per pin	—	3	
Latch-up	Minimum input voltage limit		–2.5	V
	Maximum input voltage limit		7.5	V

Table 7. ESD and Latch-Up Protection Characteristics

No.	Rating[1]	Symbol	Min	Max	Unit
1	Human body model (HBM)	V_{HBM}	±2000	—	V
2	Machine Model (MM)	V_{MM}	±200	—	V
3	Charge device model (CDM)	V_{CDM}	±500	—	V
4	Latch-up current at T_A = 85°C (applies to all pins except pin 31EXTAL1 and pin 30 XTAL1 in 80-pin package, applies to all pins except pin 23 EXTAL1 and pin 24 XTAL1 in 64-pin package)	I_{LAT}	±100[2]	—	mA
	Latch-up current at T_A = 85°C (applies to pin 31EXTAL1 and pin 30 XTAL1 in 80-pin package, applies to pin 23 EXTAL1 and pin 24 XTAL1 in 64-pin package)	I_{LAT}	±62[3]	—	mA

1 Parameter is achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted.

2 These pins meet JESD78A Class II (section 1.2) Level A (section 1.3) requirement of ±100mA.

3 This pin meets JESD78A Class II (section 1.2) Level B (section 1.3) characterization to ±62mA.

3.6 DC Characteristics

This section includes information about power supply requirements and I/O pin characteristics.

Table 8. DC Characteristics

Num	C	Characteristic		Symbol	Condition	Min	Typ[1]	Max	Unit
1		Operating Voltage				1.8		3.6	V
2	C	Output high voltage	All non-LCD pins low-drive strength	V_{OH}	V_{DD} >1.8 V, I_{Load} = –0.6 mA	V_{DD} – 0.5	—	—	V
	P		All non-LCD pins high-drive strength		V_{DD} > 2.7 V, I_{Load} = –10 mA	V_{DD} – 0.5	—	—	
	C				V_{DD} > 1.8 V, I_{Load} = –3 mA	V_{DD} – 0.5	—	—	
3	C	Output high voltage	All LCD/GPIO pins low-drive strength	V_{OH}	V_{DD} >1.8 V, I_{Load} = –0.5 mA	V_{DD} – 0.5	—	—	V
	P		All LCD/GPIO pins high-drive strength		V_{DD} > 2.7 V, I_{Load} = –2.5 mA	V_{DD} – 0.5	—	—	
	C				V_{DD} > 1.8 V, I_{Load} = –1 mA	V_{DD} – 0.5	—	—	
4	D	Output high current	Max total I_{OH} for all ports	I_{OHT}		—	—	100	mA

Table 8. DC Characteristics (continued)

Num	C	Characteristic		Symbol	Condition	Min	Typ[1]	Max	Unit
5	C	Output low voltage	All non-LCD pins low-drive strength	V_{OL}	V_{DD} > 1.8 V, I_{Load} = 0.6 mA	—	—	0.5	V
	P		All non-LCD pins high-drive strength		V_{DD} > 2.7 V, I_{Load} = 10 mA	—	—	0.5	
	C				V_{DD} > 1.8 V, I_{Load} = 3 mA	—	—	0.5	
6	C	Output low voltage	All LCD/GPIO pins low-drive strength	V_{OL}	V_{DD} > 1.8 V, I_{Load} = 0.5 mA	—	—	0.5	V
	P		All LCD/GPIO pins high-drive strength		V_{DD} > 2.7 V, I_{Load} = 3 mA	—	—	0.5	
	C				V_{DD} > 1.8 V, I_{Load} = 1 mA	—	—	0.5	
7	D	Output low current	Max total I_{OL} for all ports	I_{OLT}		—	—	100	mA
8	P	Input high voltage	all digital inputs	V_{IH}	V_{DD} > 2.7 V	0.70 x V_{DD}	—	—	V
	C				V_{DD} > 1.8 V	0.85 x V_{DD}	—	—	
9	P	Input low voltage	all digital inputs	V_{IL}	V_{DD} > 2.7 V	—	—	0.35 x V_{DD}	
	C				V_{DD} > 1.8 V	—	—	0.30 x V_{DD}	
10	C	Input hysteresis	all digital inputs	V_{hys}		0.06 x V_{DD}	—	—	mV
11	P	Input leakage current	all input only pins (per pin)	$\lvert I_{In} \rvert$	V_{In} = V_{DD} or V_{SS}	—	0.025	1	μA
12	P	Hi-Z (off-state) leakage current	all input/output (per pin)	$\lvert I_{OZ} \rvert$	V_{In} = V_{DD} or V_{SS}	—	0.025	1	μA
13	C	Total leakage current[2]	Total leakage current for all pins	$\lvert I_{InT} \rvert$	V_{In} = V_{DD} or V_{SS}	—	—	2	μA
14	P	Pullup, Pulldown resistors	all digital inputs, when enabled	R_{PU}, R_{PD}		17.5	—	52.5	kΩ
15	P	Pullup, Pulldown resistors	all digital inputs, when enabled	R_{PU}, R_{PD}		17.5	—	52.5	kΩ
16	D	DC injection current [3, 4, 5]	Single pin limit	I_{IC}	V_{IN} < V_{SS}, V_{IN} > V_{DD}	–0.2	—	0.2	mA
			Total MCU limit, includes sum of all stressed pins			–5	—	5	mA
17	C	Input Capacitance, all pins		C_{In}		—	—	8	pF
18	C	RAM retention voltage		V_{RAM}		—	0.6	1.0	V
19	C	iRTC RAM retention voltage		V_{iRAM}		—	1.05	—	V
20	C	POR re-arm voltage[6]		V_{POR}		0.9	1.4	2.0	V
21	D	POR re-arm time		t_{POR}		10	—	—	μs

Table 8. DC Characteristics (continued)

Num	C	Characteristic		Symbol	Condition	Min	Typ[1]	Max	Unit
22	C	Low-voltage detection threshold	High range — V_{DD} falling	V_{LVDH}		2.11	2.16	2.22	V
			High range — V_{DD} rising			2.16	2.23	2.27	
23	C	Low-voltage detection threshold	Low range — V_{DD} falling	V_{LVDL}		1.80	1.85	1.91	V
			Low range — V_{DD} rising			1.86	1.92	1.99	
24	C	Low-voltage warning threshold	V_{DD} falling, LVWV = 1	V_{LVWH}		2.36	2.46	2.56	V
			V_{DD} rising, LVWV = 1			2.52	2.49	2.71	
25	C	Low-voltage warning	V_{DD} falling, LVWV = 0	V_{LVWL}		2.10	2.16	2.23	V
			V_{DD} rising, LVWV = 0			2.15	2.23	2.26	
26	C	Low-voltage inhibit reset/recover hysteresis		V_{hys}		—	80	—	mV
27	P	Bandgap Voltage Reference[7]		V_{BG}		1.15	1.17	1.19	V

1 Typical values are measured at 25°C. Characterized, not tested

2 Total leakage current is the sum value for all GPIO pins. This leakage current is not distributed evenly across all pins but characterization data shows that individual pin leakage current maximums are less than 250nA.

3 All functional non-supply pins, except for PTB2 are internally clamped to V_{SS} and V_{DD}.

4 Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

5 Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If the positive injection current ($V_{In} > V_{DD}$) is greater than I_{DD}, the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure that external V_{DD} load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if clock rate is very low (which would reduce overall power consumption).

6 POR will occur below the minimum voltage.

7 Factory trimmed at V_{DD} = 3.0 V, Temp = 25°C

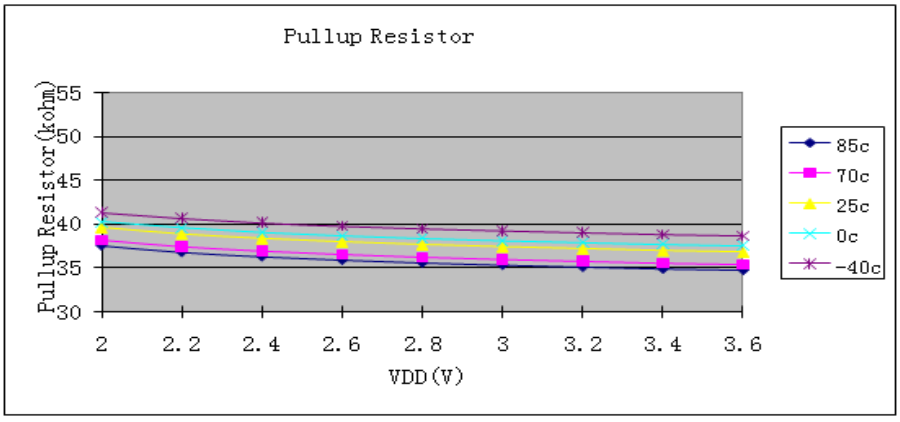


Figure 4. Non LCD pins I/O Pullup Typical Resistor Values

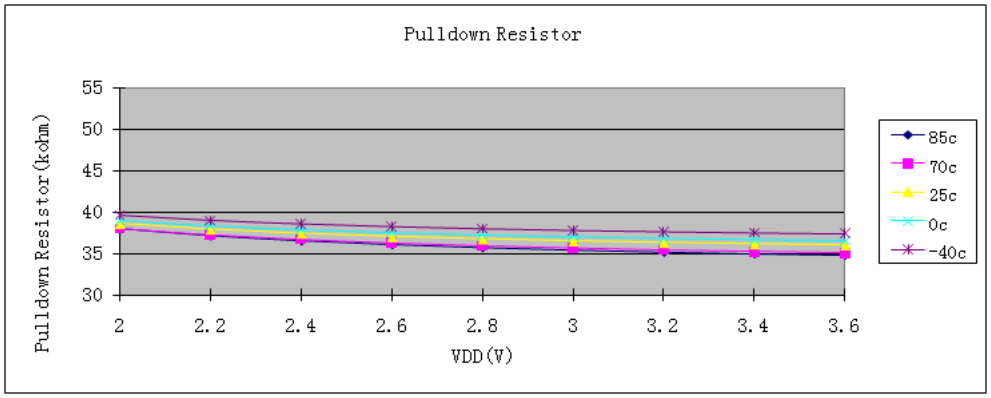
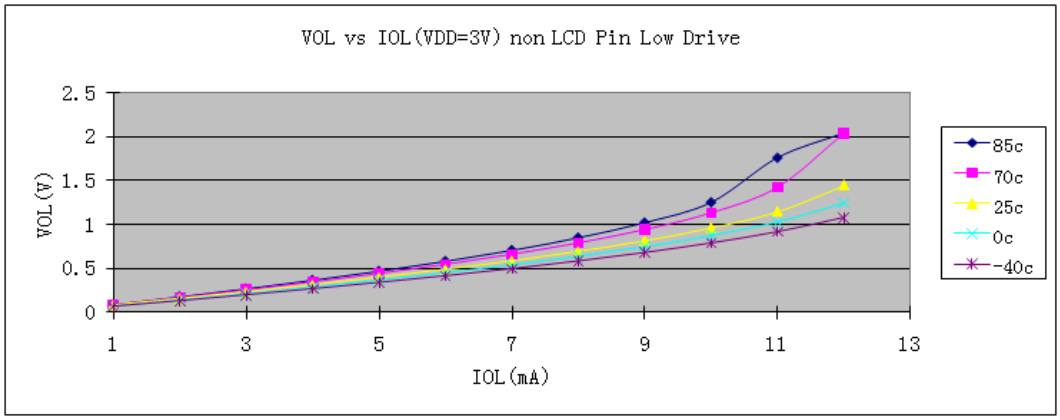


Figure 5. Non LCD pins I/O Pulldown Typical Resistor Values



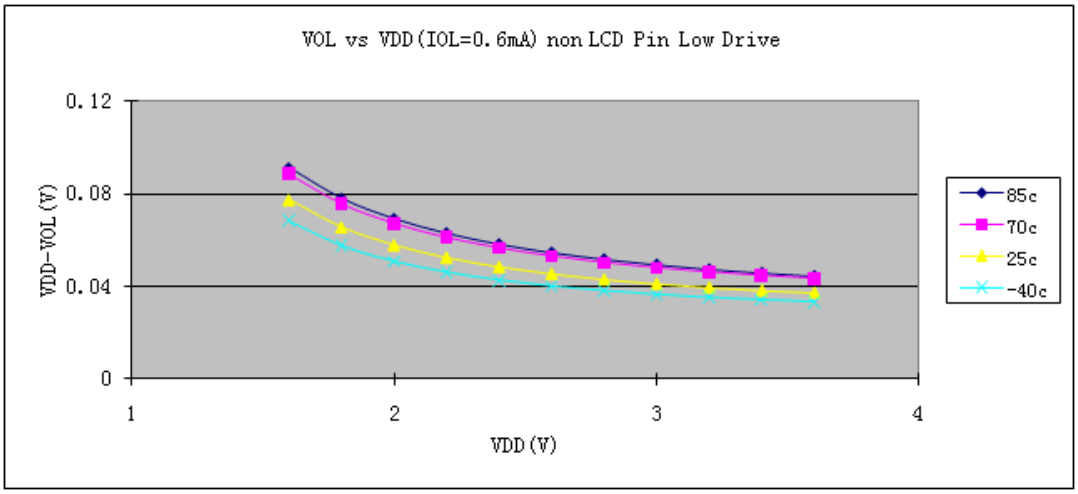
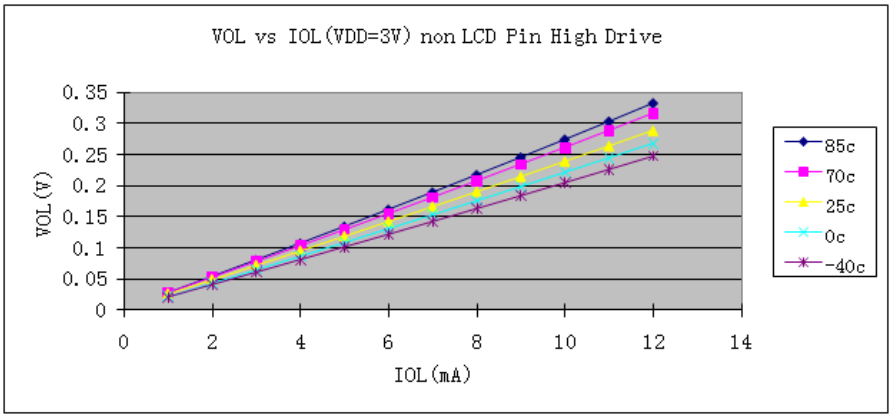


Figure 6. Typical Low-Side Driver (Sink) Characteristics(Non LCD pins) — Low Drive (PTxDSn = 0)



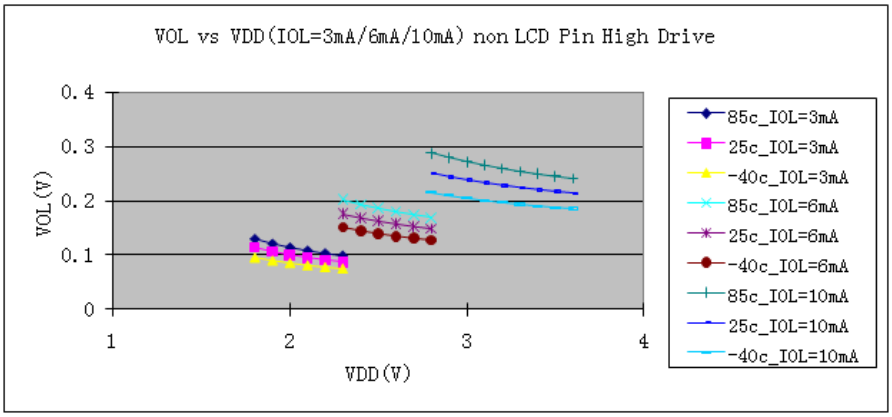


Figure 7. Typical Low-Side Driver (Sink) Characteristics(Non LCD pins) — High Drive (PTxDSn = 1)

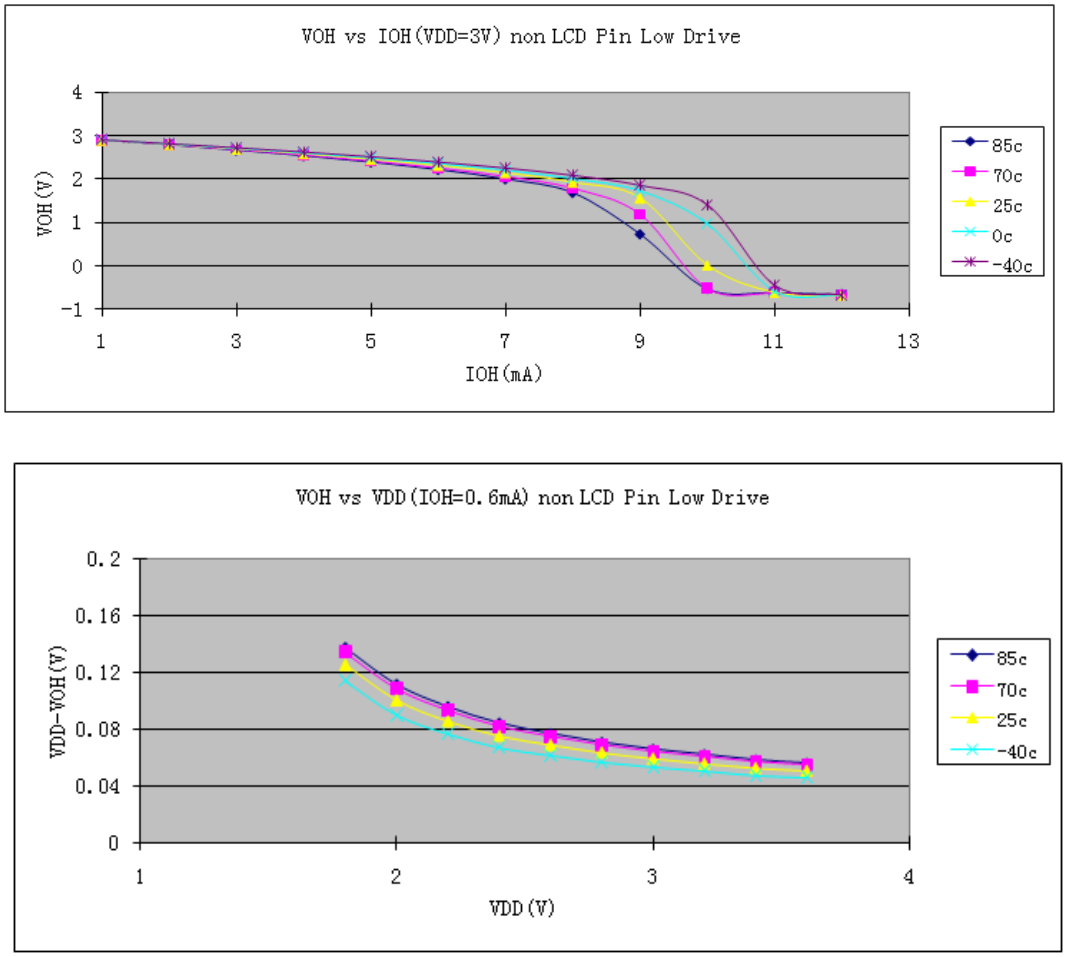
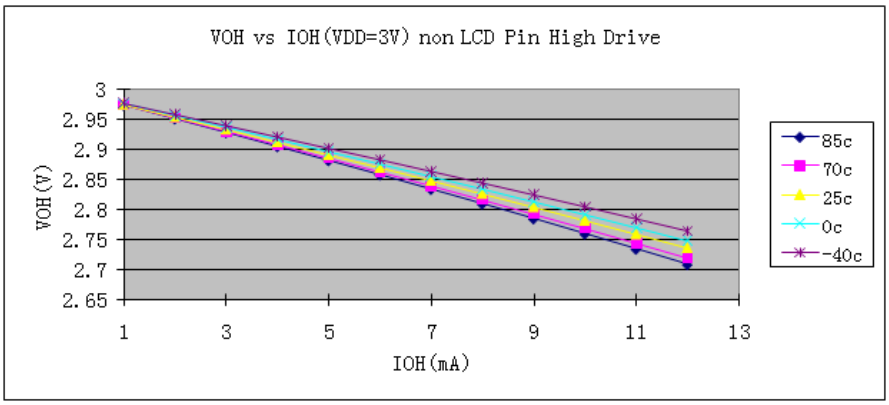


Figure 8. Typical High-Side (Source) Characteristics (Non LCD pins)— Low Drive (PTxDSn = 0)



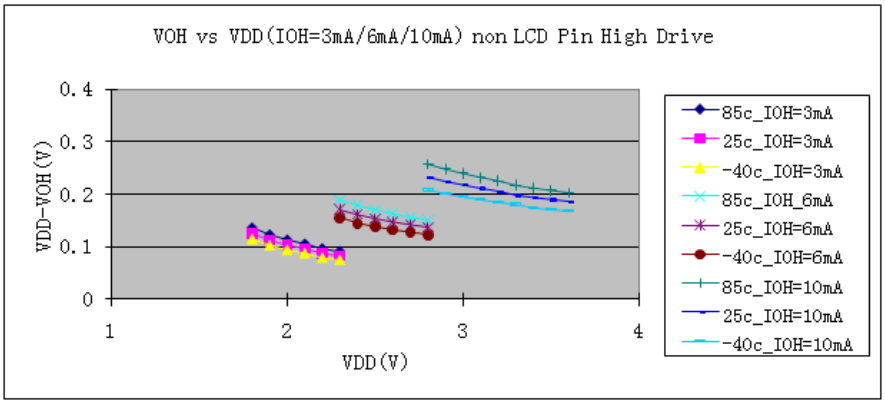


Figure 9. Typical High-Side (Source) Characteristics(Non LCD pins) — High Drive (PTxDSn = 1)

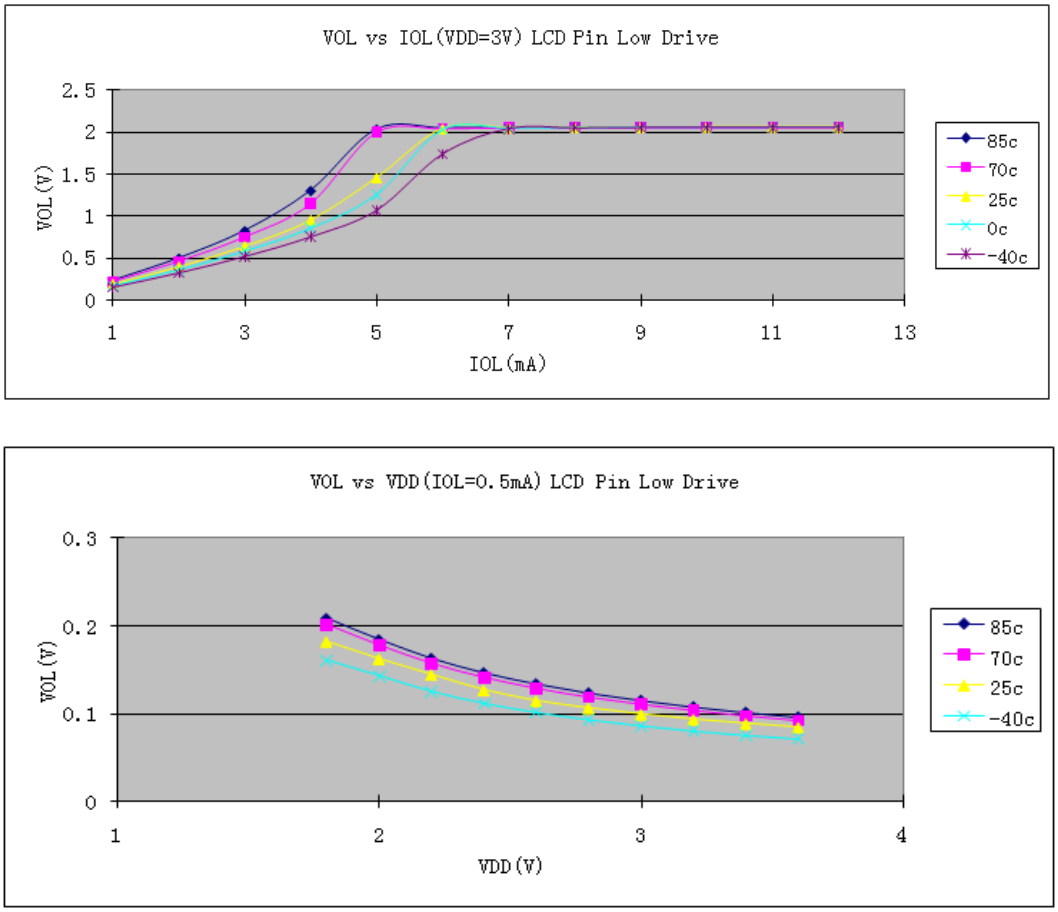
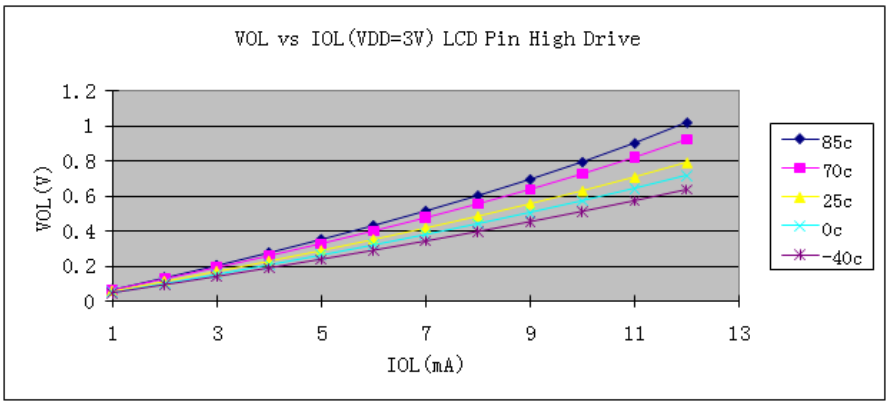


Figure 10. Typical Low-Side Driver (Sink) Characteristics(LCD/GPIO pins) — Low Drive (PTxDSn = 0)



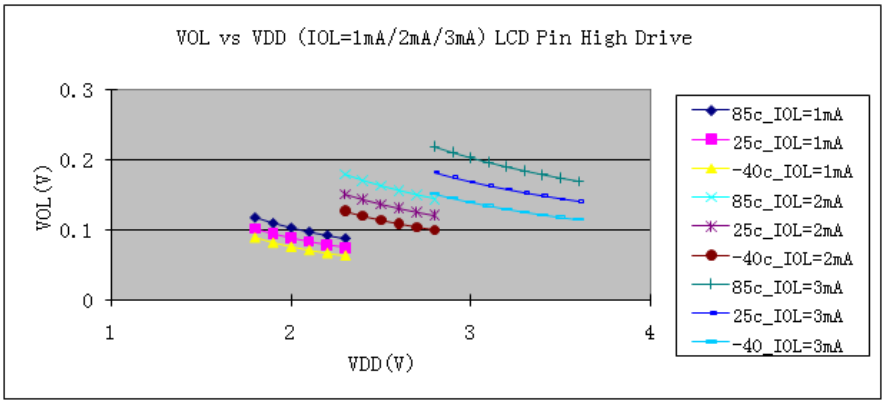


Figure 11. Typical Low-Side Driver (Sink) Characteristics(LCD/GPIO pins) — High Drive (PTxDSn = 1)

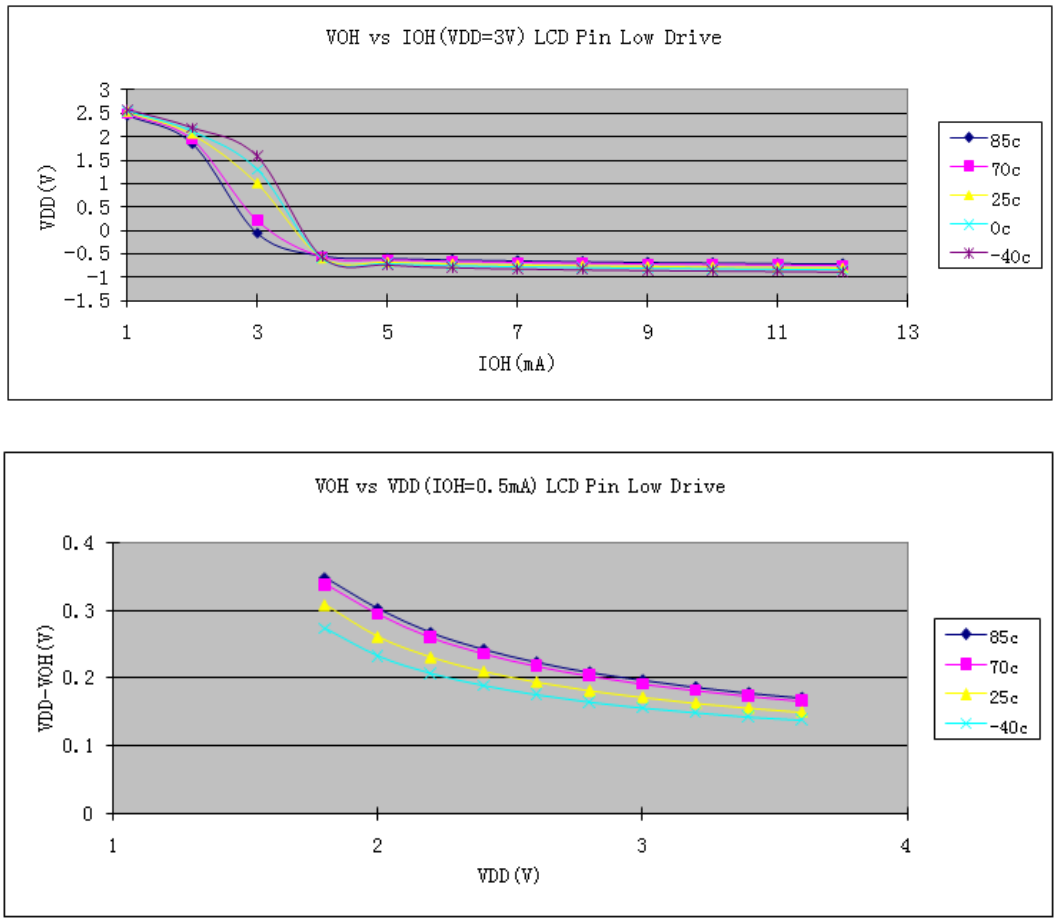
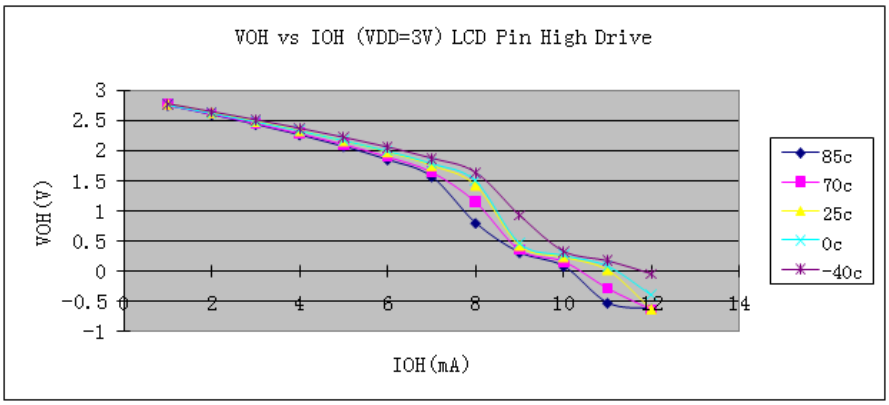


Figure 12. Typical High-Side (Source) Characteristics (LCD/GPIO pins)— Low Drive (PTxDSn = 0)



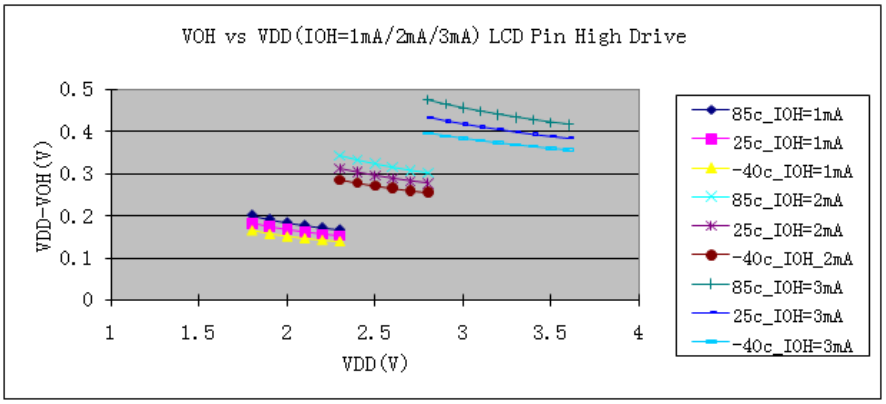


Figure 13. Typical High-Side (Source) Characteristics(LCD/GPIO pins) — High Drive (PTxDSn = 1)

3.7 Supply Current Characteristics

This section includes information about power supply current in various operating modes.

Table 9. Supply Current Characteristics

Num	C	Parameter	Symbol	Bus Freq	V_{DD} (V)	Typ[1]	Max	Unit	Temp (°C)
1	C	Run supply current FEI mode, all modules on, running from Flash	RI_{DD}	20 MHz	3	17.4	20.5	mA	–40 to 85°C
	T			2 MHz		2.6	—		
2	C	Run supply current FEI mode, all modules off, running from Flash	RI_{DD}	20 MHz	3	10.5	—	mA	–40 to 85°C
	T			2 MHz		1.6	—		
3	T	Run supply current LPRS=0, all modules off, running from Flash	RI_{DD}	16 kHz FBILP	3	158	—	µA	–40 to 85°C
	T			16 kHz FBELP		148	—		
4	T	Run supply current LPRS=1, all modules off; running from Flash	RI_{DD}	16 kHz FBILP	3	160	—	µA	–40 to 85°C
	T			16 kHz FBELP		23	—		

Table 9. Supply Current Characteristics

Num	C	Parameter	Symbol	Bus Freq	V_{DD} (V)	Typ[1]	Max	Unit	Temp (°C)
5	T	Run supply current LPRS=1, all modules off; running from RAM	RI_{DD}	16 kHz FBILP	3	137	—	μA	–40 to 85°C
	T			16 kHz FBELP		8	—		
6	C	Wait mode supply current, all modules off	WI_{DD}	20 MHz	3	5.4	7.5	mA	–40 to 85°C
	C			2 MHz		1.1	—		
7	T	Wait mode supply current LPRS = 0, all modules off	WI_{DD}	16 kHz FBILP	3	131	—	μA	–40 to 85°C
	T			16 kHz FBELP	3	123	—	μA	–40 to 85°C
8	T	Wait mode supply current LPRS = 1, all modules off	WI_{DD}	16 kHz FBILP	3	159	—	μA	–40 to 85°C
	T			16 kHz FBELP	3	5.6	—	μA	–40 to 85°C
9	C	Stop2 mode supply current	$S2I_{DD}$	N/A	3	330	1000	nA	–40 to 25°C
						1622	—		70°C
						6000	—		85°C
	C			N/A	2	—	—		–40 to 25°C
						—	—		70°C
						—	—		85°C
10	C	Stop3 mode supply current No clocks active	$S3I_{DD}$	N/A	3	474	1100	nA	–40 to 25°C
						2608	—		70°C
						9000	—		85°C
	C			N/A	2	—	—		–40 to 25°C
						—	—		70°C
						—	—		85°C

[1] Typical values are measured at 25°C. Characterized, not tested.

Table 10. Stop Mode Adders (V_{DD}=3V, V_{DDA}=V_{DD})

Num	C	Parameter	Condition	Temperature (°C)				Units
				-40	25	70	85	
1	C	LPO		100	100	150	175	nA
2	C	ERREFSTEN	RANGE = HGO = 0	600	737	830	863	nA
3	C	IREFSTEN[1]		—	73	80	92	μA
4	C	LVD[1]	LVDSE = 1	110	112	112	113	μA
5	C	PRACMP[1]	Not using the bandgap (BGBE = 0), PRG enabled	30	35	40	55	μA

Table 10. Stop Mode Adders (continued)(V_{DD}=3V, V_{DDA}=V_{DD})

Num	C	Parameter	Condition	Temperature (°C)				Units
				-40	25	70	85	
6	C	VREFO	Not using the bandgap (BGBE = 0), in tight regulation mode	264	286	296	298	μA
7	C	IRTC		1.4	1.65	2.01	2.27	μA
8	C	ADC[1]	ADLPC = ADLSMP = 1 Not using the bandgap (BGBE = 0), single conversion	78.1	88.5	92.6	93.6	μA
9	C	LCD	VIREG enabled for Contrast control, 1/8 Duty cycle, 8x24 configuration for driving 192 Segments, 32Hz frame rate, No LCD glass connected.	0.67	0.88	3.74	7.16	μA
10	C	PCNT[1]	32KHz clock, without PWM output	33	47	67	77	nA
11	C	PCNT[1]	32KHz clock, with PWM output	40	50	63	77	nA

[1] Not available in stop2 mode.